# **BAV99** series

# High-speed switching diodes Rev. 8 — 18 November 2010

Product data sheet

#### 1. **Product profile**

#### 1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview** 

Type number	Package			Configuration Package	
	NXP	JEITA	JEDEC		configuration
BAV99	SOT23	-	TO-236AB	dual series	small
BAV99S	SOT363	SC-88	-	quadruple; 2 series	very small
BAV99W	SOT323	SC-70	-	dual series	very small

#### 1.2 Features and benefits

- High switching speed: t<sub>rr</sub> ≤ 4 ns
- Low leakage current
- Small SMD plastic packages
- Low capacitance: C<sub>d</sub> ≤ 1.5 pF
- Reverse voltage: V<sub>R</sub> ≤ 100 V
- AEC-Q101 qualified

#### 1.3 Applications

- High-speed switching
- General-purpose switching
- Reverse polarity protection

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>R</sub>	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
$V_R$	reverse voltage		-	-	100	V
t <sub>rr</sub>	reverse recovery time		[1] -	-	4	ns

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.



## 2. Pinning information

Table 3. Pinning

14510 0.	·9		
Pin	Description	Simplified outline	Graphic symbol
BAV99; E	BAV99W		
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2 006aaa144	
			006aaa763

BAV99S	3		
1	anode (diode 1)	П- П- П.	
2	cathode (diode 2)	6 5 4	6 5 4
3	cathode (diode 3), anode (diode 4)	0	
4	anode (diode 3)	1 2 3	本
5	cathode (diode 4)		1 2 3
6	cathode (diode 1), anode (diode 2)		006aab101

## 3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
BAV99	-	plastic surface-mounted package; 3 leads	SOT23
BAV99S	SC-88	plastic surface-mounted package; 6 leads	SOT363
BAV99W	SC-70	plastic surface-mounted package; 3 leads	SOT323

## 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
BAV99	A7*
BAV99S	K1*
BAV99W	A7*

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_{RRM}$	repetitive peak reverse voltage		-	100	V
$V_R$	reverse voltage		-	100	V
I <sub>F</sub>	forward current				
	BAV99		<u>[1]</u> -	215	mA
			[2] _	125	mA
	BAV99S		<u>[1]</u> -	200	mA
	BAV99W		<u>[1]</u> -	150	mA
			[2] _	130	mA
I <sub>FRM</sub>	repetitive peak forward current		-	500	mA
I <sub>FSM</sub>	non-repetitive peak	square wave	<u>[3]</u>		
	forward current	$t_p = 1 \mu s$	-	4	А
		$t_p = 1 \text{ ms}$	-	1	А
		t <sub>p</sub> = 1 s	-	0.5	А
P <sub>tot</sub>	total power dissipation		<u>[1][4]</u>		
	BAV99	$T_{amb} \le 25  ^{\circ}C$	-	250	mW
	BAV99S	$T_{sp} \le 85  ^{\circ}C$	<u>[5]</u> _	250	mW
	BAV99W	$T_{amb} \le 25  ^{\circ}C$	-	200	mW
Per device					
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Single diode loaded.

<sup>[2]</sup> Double diode loaded.

<sup>[3]</sup>  $T_i = 25$  °C prior to surge.

<sup>[4]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[5]</sup> Soldering points at pins 2, 3, 5 and 6.

#### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air	[1][2]			
	BAV99		-	-	500	K/W
	BAV99W		-	-	625	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BAV99		-	-	360	K/W
	BAV99S		[3]	-	260	K/W
	BAV99W		-	-	300	K/W

<sup>[1]</sup> Single diode loaded.

#### 7. Characteristics

Table 8. Characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	9					
$V_{F}$	forward voltage	I <sub>F</sub> = 1 mA	-	-	715	mV
	I <sub>F</sub> = 10 mA	-	-	855	mV	
		$I_F = 50 \text{ mA}$	-	-	1	V
		I <sub>F</sub> = 150 mA	-	-	1.25	V
$I_R$	reverse current	V <sub>R</sub> = 25 V	-	-	30	nA
		V <sub>R</sub> = 80 V	-	-	0.5	μΑ
		$V_R = 25 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	30	μΑ
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
$C_d$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	-	4	ns
$V_{FR}$	forward recovery voltage		[2] _	-	1.75	V

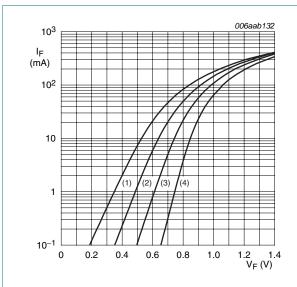
<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[3]</sup> Soldering points at pins 2, 3, 5 and 6.

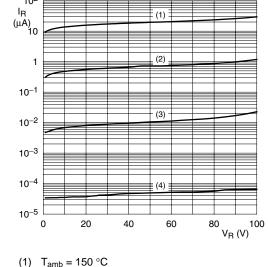
<sup>[2]</sup> When switched from  $I_F = 10$  mA;  $t_r = 20$  ns.

006aab133



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

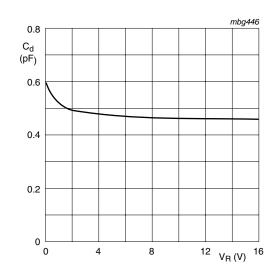
Forward current as a function of forward Fig 1. voltage; typical values



10<sup>2</sup>

- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

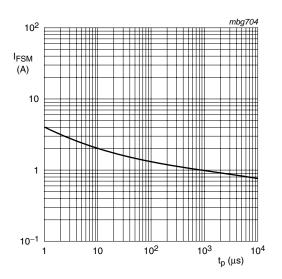
Reverse current as a function of reverse Fig 2. voltage; typical values



Diode capacitance as a function of reverse

 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

voltage; typical values



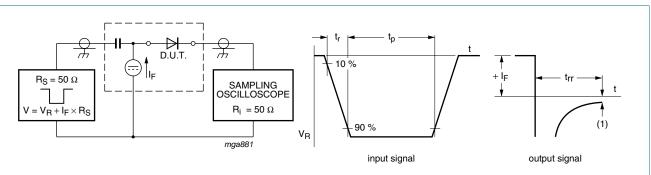
Based on square wave currents.

T<sub>i</sub> = 25 °C; prior to surge

Fig 4. Non-repetitive peak forward current as a function of pulse duration; maximum values

Fig 3.

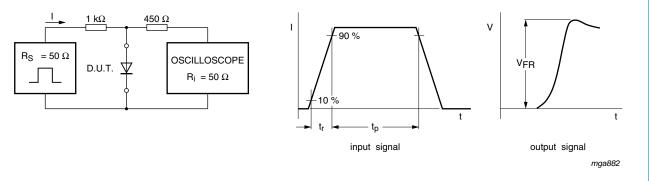
#### 8. Test information



(1)  $I_R = 1 \text{ mA}$ 

Input signal: reverse pulse rise time  $t_r$  = 0.6 ns; reverse voltage pulse duration  $t_p$  = 100 ns; duty cycle  $\delta$  = 0.05 Oscilloscope: rise time  $t_r$  = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



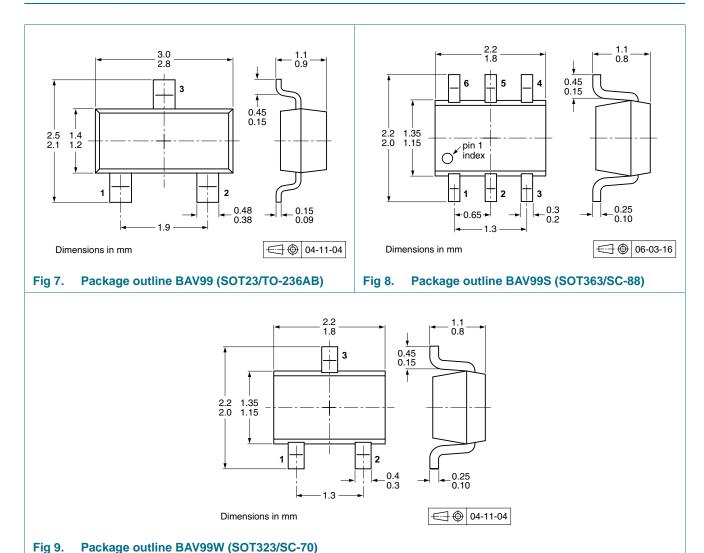
Input signal: forward pulse rise time  $t_r$  = 20 ns; forward current pulse duration  $t_p \ge 100$  ns; duty cycle  $\delta \le 0.005$ 

Fig 6. Forward recovery voltage test circuit and waveforms

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



## 10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	ype number Package Description		Packing quantity	
			3000	10000
BAV99	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
BAV99S SOT363		4 mm pitch, 8 mm tape and reel; T1 [2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	-125	-165
BAV99W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

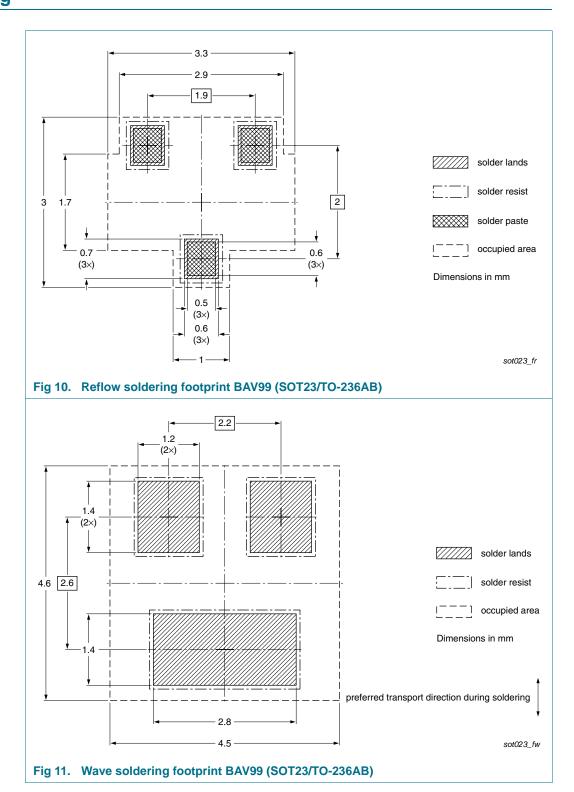
[3] T2: reverse taping

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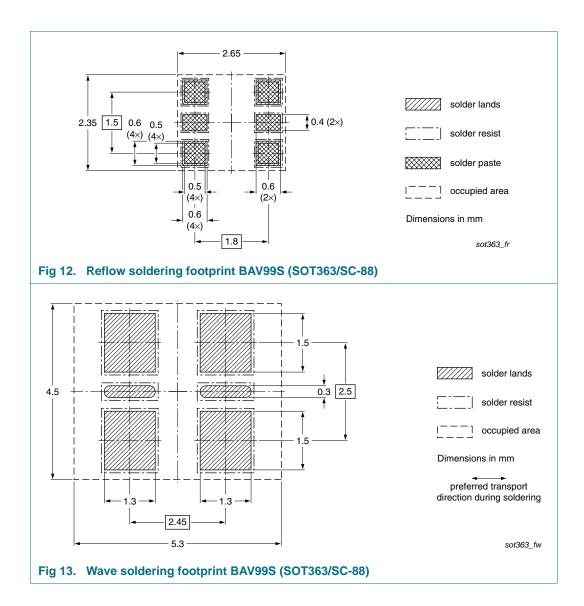
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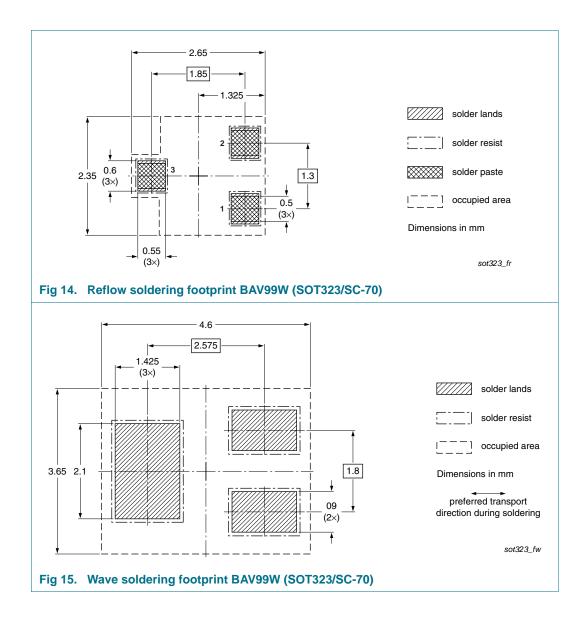
## 11. Soldering



#### **High-speed switching diodes**



#### **High-speed switching diodes**



#### High-speed switching diodes

## 12. Revision history

#### Table 10. Revision history

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV99_SER_8	20101118	Product data sheet	-	BAV99_SER_7
Modifications:	<ul> <li>Section 4 "M</li> </ul>	arking": marking placeholder e	explanation in table for	ooter updated
	<ul> <li>Section 5 "Li</li> </ul>	miting values": Ptot condition for	or BAV99S corrected	
	<ul> <li>Section 13 "L</li> </ul>	<u>egal information</u> ": updated		
BAV99_SER_7	20100414	Product data sheet	-	BAV99_SER_6
BAV99_SER_6	20100310	Product data sheet	-	BAV99_SER_5
BAV99_SER_5	20080820	Product data sheet	-	BAV99_4
				BAV99S_3 BAV99W 4
PA\/00_4	20011015	Draduat appoification		BAV99 3
BAV99_4	20011015	Product specification	•	DAV99_3
BAV99S_3	20010514	Product specification	-	BAV99S_N_2
BAV99W_4	19990511	Product specification	-	BAV99W_3

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#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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**BAV99** series

#### **High-speed switching diodes**

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## **BAV99** series

#### **High-speed switching diodes**

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